

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

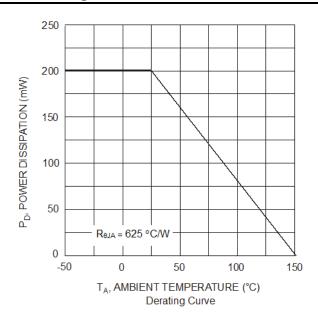
Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		Vcc	50	V
Input Voltage, (1) to (2)	DDTD122TU DDTD142TU	V _{IN}	-5 to +6 -5 to +6	V
Input Voltage, (2) to (1)	DDTD122TU DDTD142TU	VEBO(MAX)	5	V
Output Current	All	lc	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	Reja	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Note: 5. Mounted on FR4 PC Board with minimum recommended pad layout.

Power Derating Curve





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

R1 & R2 Types

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDTD122LU DDTD142JU	VI(off)	0.3 0.3		_	V	V _{CC} = 5V, I _O = 100µA
	DDTD122LU DDTD142JU	VI(on)	_	_	2.0 2.0	V	Vo = 0.3V, Io = 20mA Vo = 0.3V, Io = 20mA
Output Voltage		Vo(on)		—	0.3	V	Io/II = 50mA/2.5mA
Input Current	DDTD122LU DDTD142JU	lı			28 13	mA	Vi = 5V
Output Current		I _{O(off)}	—		0.5	μA	$V_{CC} = 50V, V_I = 0V$
DC Current Gain	DDTD122LU DDTD142JU	Gı	56 56			_	Vo = 5V, lo = 50mA
Gain-Bandwidth Product (Note 6)		f⊤		200	_	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

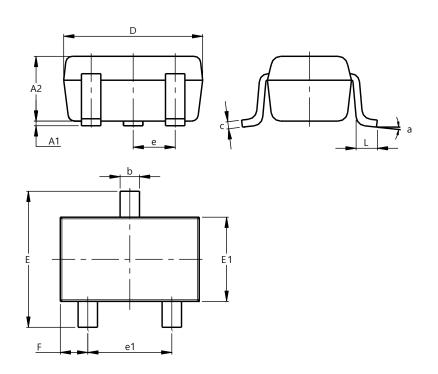
Electrical Characteristics (@T _A = +25°C, unless otherwise specified.)						R1-Only Types		
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage		ВУсво	50	_	—	V	Ic = 50µA	
Collector-Emitter Breakdown Voltage		BV _{CEO}	40	_	_	V	I _C = 1mA	
Emitter-Base Breakdown Voltage	DDTD122TU DDTD142TU	ВV _{ЕВО}	5			V	Iε = 50μΑ Iε = 50μΑ	
Collector Cutoff Current		I _{CBO}	_		0.5	μA	V _{CB} = 50V	
Emitter Cutoff Current	DDTD122TU DDTD142TU	IEBO			0.5 0.5	μA	V _{EB} = 4V	
Collector-Emitter Saturation Voltage		Vce(sat)	_	_	0.3	V	Ic = 50mA, I _B = 2.5mA	
DC Current Transfer Ratio	DDTD122TU DDTD142TU	hfe	100 100	250 250	600 600	_	Ic = 5mA, Vce = 5V	
Gain-Bandwidth Product (Note 6)		f⊤		200	_	MHz	$V_{CE} = 10V, I_E = 5mA, f = 100MHz$	

Note: 6. Transistor - for reference only.



Package Outline Dimensions

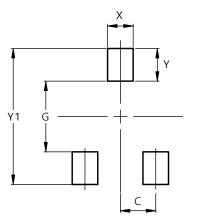
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
E	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0.650 BSC						
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	1.300			
Х	0.470			
Y	0.600			
Y1	2.500			

SOT323

SOT323



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